

UNISONIC TECHNOLOGIES CO., LTD

UT60N03 **Power MOSFET**

30V, 60A N-CHANNEL LOGIC LEVEL MOSFET

DESCRIPTION

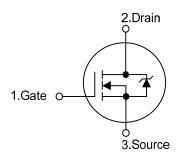
This device employs advanced MOSFET technology and features low gate charge while maintaining low on-resistance.

Optimized for switching applications, this device improves the overall efficiency of DC/DC converters and allows operation to higher switching frequencies.

FEATURES

- * $R_{DS(ON)}$ < 23m Ω @ V_{GS} =10V, I_D =30A
- * $R_{DS(ON)}$ < 30m Ω @ V_{GS} =4.5V, I_{D} =19A
- * Low Capacitance
- * Low Gate Charge
- * Fast Switching Capability
- * Avalanche Energy Specified

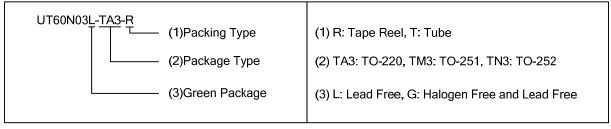
SYMBOL



ORDERING INFORMATION

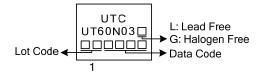
Ordering	Dookogo	Pin Assignment			Dooking		
Lead Free	Halogen Free	Package	1	2	3	Packing	
UT60N03L-TA3-T	UT60N03G-TA3-T	TO-220	G	D	S	Tube	
UT60N03L-TM3-T	UT60N03G-TM3-T	TO-251	G	D	S	Tube	
UT60N03L-TN3-R	UT60N03G-TN3-R	TO-252	G	D	S	Tape Reel	
UT60N03L-TND-R	UT60N03G-TND-R	TO-252D	G	D	S	Tape Reel	

Note: Pin Assignment: G: Gate D: Drain S: Source



TO-220 TO-251 TO-252

MARKING



UT60N03 Power MOSFET

■ ABSOLUTE MAXIMUM RATINGS (T_C=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT	
Drain-Source Voltage		V_{DSS}	30	V	
Gate-Source Voltage		V_{GSS}	±20	V	
Continuous Drain Current (V _{GS} =10V)		I _D	60	Α	
Power Dissipation	TO-220	P _D	60	W	
	TO-251/TO-252		45		
Derate above 25°C	TO-220		0.4	\\\\\°C	
	TO-251/TO-252		0.37	W/°C	
Junction Temperature		TJ	+150	°C	
Storage Temperature		T _{STG}	-55 ~ + 150	°C	

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL RESISTANCES CHARACTERISTICS

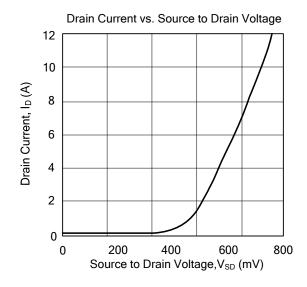
PARAMETER		SYMBOL	RATINGS	UNIT	
Junction to Ambient	TO-220	0	62.5	°C/W	
	TO-251/TO-252	θ _{JA}	100		
Junction to Case	TO-220	0	2.5	°C/W	
	TO-251/TO-252	θις	2.73		

■ ELECTRICAL CHARACTERISTICS (T_C=25°C, unless otherwise specified)

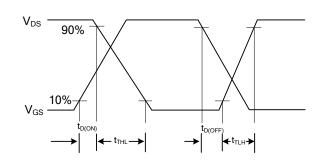
PARAMETER		SYMBOL	TEST CONDITIONS		TYP	MAX	UNIT
OFF CHARACTERISTICS	<u> </u>			l		<u>I</u>	
Drain-Source Breakdown Voltage		BV _{DSS}	V _{GS} =0V, I _D =250μA				٧
Drain-Source Leakage Current		I _{DSS}	V _{DS} =25V, V _{GS} =0V			1	μA
Gate-Source Leakage Current		I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA
ON CHARACTERISTICS							
Gate Threshold Voltage		$V_{GS(TH)}$	$V_{DS}=V_{GS}$, $I_D=250\mu A$	1		3	٧
Static Drain Course On Besisters		В	V _{GS} =10V, I _D =30A		14	23	m0
Static Drain-Source On-Resistance		R _{DS(ON)}	V _{GS} =4.5V, I _D =19A		24	30	mΩ
DYNAMIC PARAMETERS							
Input Capacitance		C_{ISS}	V _{DS} =15V, V _{GS} =0V, f=1MHz		900		pF
Output Capacitance		Coss			210		pF
Reverse Transfer Capacitance		C_{RSS}			90		pF
SWITCHING PARAMETERS							
Turn-ON Time		$t_{(ON)}$				90	ns
Turn-ON Delay Time		$t_{D(ON)}$			11		ns
Turn-ON Rise Time Turn-OFF Time Turn-OFF Delay Time Turn-OFF Fall-Time		t_{R}	V _{DD} =15V, I _D =7.9A, R _L =18Ω, V _{GS} =4.5V		49		ns
		$t_{(OFF)}$	VDD=13V, ID=7.9A, KL=1022, VGS=4.3V			83	ns
		$t_{D(OFF)}$			27		ns
		t _F			28		ns
Turn-ON Time		$t_{(ON)}$				48	ns
Turn-ON Delay Time		$t_{D(ON)}$			6		ns
Turn-ON Rise Time Turn-OFF Time		t_{R}	V_{DD} =15V, I_{D} =7.9A, R_{L} =18 Ω , V_{GS} =10V		26		ns
		$t_{(OFF)}$				120	ns
Turn-OFF Delay Time		$t_{D(OFF)}$			52		ns
Turn-OFF Fall-Time		t_{F}]		28		ns
Total Cate Charge	/	Q_{G}	V _{GS} =0V~5V,V _{DD} =15V,I _D =19A I _G =1.0mA		18	28	nC
Total Gate Charge	0V	Q G	V _{GS} =0V~10V,V _{DD} =15V,I _D =19A,I _G =1.0mA		9.6	14	IIC
Threshold Gate Charge		$Q_{G(TH)}$	V _{GS} =0V~1V,V _{DD} =15V,I _D =19A I _G =1.0mA		1.0	1.5	nC
		Q_GS	V _{DD} =15V, I _D =19A I _G =1.0mA		3.4		nC
		Q_GD	VDD		3.4		nC
SOURCE- DRAIN DIODE RATIN	NGS A	ND CHA	RACTERISTICS				
Drain-Source Diode Forward Voltage		e V _{SD}	I _{SD} =19A			1.25	V
			I _{SD} =10A			1.0	V
Reverse Recovery Time		t _{rr}	-I _{SD} =9A, dI _S /dt =100A/s,			58	ns
Reverse Recovery Charge		Q_{RR}				70	nC

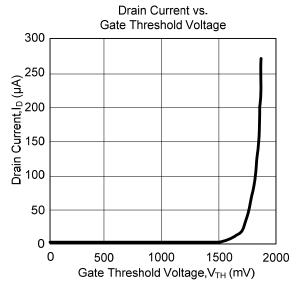
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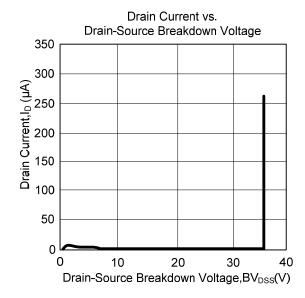
■ TYPICAL CHARACTERISTICS

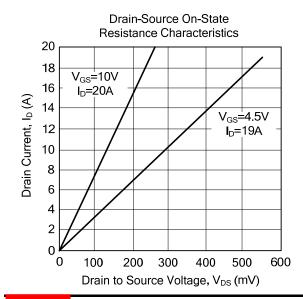


Switching Time Waveforms









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